

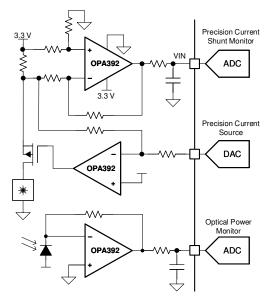
OPAx392 Precision, Low-Offset-Voltage, Low-Noise, Low-Input-Bias-Current, Rail-to-Rail I/O, e-trim™ Operational Amplifiers

1 Features

- Low offset voltage: ±10µV (maximum)
- Low-drift: ±0.18µV/°C
- Low input bias current: 10fA
- Low noise: $4.4 \text{nV}/\sqrt{\text{Hz}}$ at 10 kHz
- Low 1/f noise: 2µV_{PP} (0.1Hz to 10Hz)
- Low supply voltage operation: 1.7V to 5.5V
- Low quiescent current: 1.22mA
- Fast settling: 0.75µs (1V to 0.1%)
- Fast slew rate: 4.5V/µs
- High output current: +65mA/–55mA short circuit
- Gain bandwidth: 13MHz
- · Rail-to-rail input and output
- Specified temperature range: -40°C to +125°C
- EMI and RFI filtered inputs

2 Applications

- Multiparameter patient monitor
- Electrocardiogram (ECG)
- Chemistry and gas analyzer
- Optical module
- Analog input module
- Process analytics (pH, gas, concentration, force and humidity)
- Gas detector
- Analog security camera
- Merchant DC/DC
- Pulse oximeter
- Inter-DC interconnect (long-haul, submarine)
- Data acquisition (DAQ)



OPAx392 Applications in Optical Modules

3 Description

The OPAx392 family of operational amplifiers (OPA392, OPA2392, and OPA4392) features ultra-low offset, offset drift, and input bias current with rail-to-rail input and output operation. In addition to precision dc accuracy, the ac performance is optimized for low noise and fast-settling transient response. These features make the OPAx392 an excellent choice for driving high-precision analog-to-digital converters (ADCs) or buffering the output of high-resolution, digital-to-analog converters (DACs).

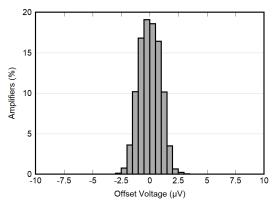
The OPAx392 feature TI's e-trim[™] operational amplifier technology to achieve ultra-low offset voltage and offset voltage drift without any input chopping or auto-zero techniques. This technique enables ultra-low input bias current for sensor inputs or photodiode current-to-voltage measurements, creating high-performance transimpedance stages for optical modules or medical instrumentation.

PART NUMBER ⁽¹⁾ CHANNELS PACKAGE ⁽²⁾						
	Single	DBV (SOT-23, 5)				
OPA392	Single	DCK (SC70, 5)				
	Single	YBJ (DSBGA, 6)				
	Dual	D (SOIC, 8)				
OPA2392	Dual	DGK (VSSOP, 8)				
OFA2392	Dual	DSG (WSON, 8)				
	Dual	YBJ (DSBGA, 9)				
OPA4392 ⁽³⁾	Quad	PW (TSSOP, 14) ⁽³⁾				
	Quad	RTE (WQFN, 16) ⁽³⁾				

(1) See Section 4.

(2) For more information, see Section 11.

(3) Preview information (not Production Data).



OPAx392 Input Offset Voltage Distribution

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. UNLESS OTHERWISE NOTED, this document contains PRODUCTION DATA.



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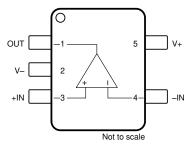
4 Device Comparison Table

DEVICE	CHANNELS	SHUTDOWN	PACKAGE	
		No	DBV (SOT-23, 5)	
OPA392	Single	No	DCK (SC70, 5)	
	Yes No No	YBJ (DSBGA, 6)		
	No	No	D (SOIC, 8)	
OPA2392			DGK (VSSOP, 8)	
UPA2392	Duai	No DSG (WSON, 8	DSG (WSON, 8)	
			Yes	YBJ (DSBGA, 9)
OPA4392 ⁽¹⁾	Quad	No	PW (TSSOP, 14) ⁽¹⁾	
UFA4392\''	Quad	Yes	RTE (WQFN, 16) ⁽¹⁾	

(1) Preview information (not Production Data).



5 Pin Configuration and Functions



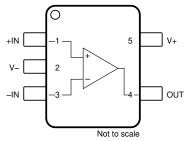


Figure 5-1. OPA392 DBV Package, 5-Pin SOT-23 (Top View)



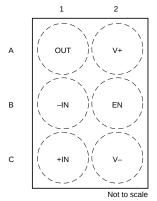
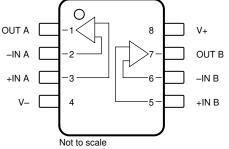
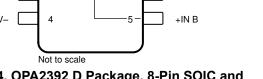


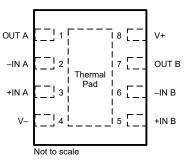
Figure 5-3. OPA392 YBJ Package, 6-Pin DSBGA (Top View)

		PIN			
NAME	NO.			TYPE	DESCRIPTION
	DBV (SOT-23)	DCK (SC70)	YBJ (DSBGA)		
EN	—	—	B2	Input	Enable pin. High = amplifier enabled.
-IN	4	3	B1	Input	Inverting input
+IN	3	1	C1	Input	Noninverting input
OUT	1	4	A1	Output	Output
V–	2	2	C2	Power	Negative (lowest) power supply
V+	5	5	A2	Power	Positive (highest) power supply









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Figure 5-5. OPA2392 DSG Package, 8-Pin WSON With Exposed Thermal Pad (Top View)

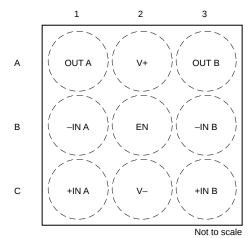
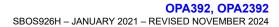
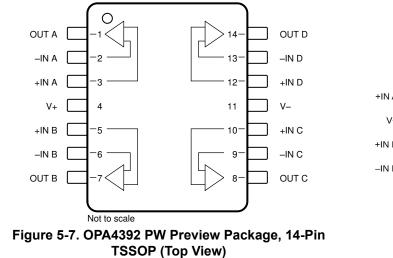


Figure 5-6. OPA2392 YBJ Package, 9-Pin DSBGA (Top View)

	i	PIN				
	NO.			TYPE	DESCRIPTION	
NAME	D (SOIC), DGK (VSSOP)	DSG (WSON)	YBJ (DSBGA)			
EN			B2	Input	Enable pin. High = both amplifiers enabled.	
–IN A	2	2	B1	Input	Inverting input, channel A	
+IN A	3	3	C1	Input	Noninverting input, channel A	
–IN B	6	6	B3	Input	Inverting input, channel B	
+IN B	5	5	C3	Input	Noninverting input, channel B	
OUT A	1	1	A1	Output	Output, channel A	
OUT B	7	7	A3	Output	Output, channel B	
V–	4	4	C2	Power	Negative (lowest) power supply	
V+	8	8	A2	Power	Positive (highest) power supply	
Thermal Pad	—	Thermal pad	_	_	Connect thermal pad to V–	







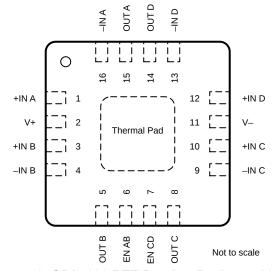


Figure 5-8. OPA4392 RTE Preview Package, 16-Pin WQFN (Top View)

	PIN				
NAME	NO.		TYPE	DESCRIPTION	
NAME	PW (TSSOP)	RTE (WQFN)			
EN AB	_	6	Input	Enable pin for A and B amplifiers. High = amplifiers A and B are enabled.	
EN CD	_	7	Input	Enable pin for C and D amplifiers. High = amplifiers C and D are enabled.	
–IN A	2	16	Input	Inverting input, channel A	
+IN A	3	1	Input	Noninverting input, channel A	
–IN B	6	4	Input	Inverting input, channel B	
+IN B	5	3	Input	Noninverting input, channel B	
–IN C	9	9	Input	Inverting input, channel C	
+IN C	10	10	Input	It Noninverting input, channel C	
–IN D	13	13	Input	out Inverting input, channel D	
+IN D	12	12	Input	Noninverting input, channel D	
OUT A	1	15	Output	Output, channel A	
OUT B	7	5	Output	Output, channel B	
OUT C	8	8	Output	Output, channel C	
OUT D	14	14	Output	Output, channel D	
Thermal Pad	_	Thermal Pad	Power	Connect thermal pad to V–	
V–	11	11	Power	Negative (lowest) power supply	
V+	4	2	Power	Positive (highest) power supply	

Table 5-3. Pin Functions: OPA4392



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT	
Vs	$\sum_{i=1}^{n} \sum_{j=1}^{n} \frac{1}{2} \left(\frac{1}{2} - \frac{1}{2} \right) \left(\frac{1}{2} - \frac{1}{2} \right)$	Single-supply		6	V	
	Supply voltage, $V_S = (V+) - (V-)$	Dual-supply		±3	v	
	Input voltage, all pins	Common-mode	(V–) – 0.5	(V+) + 0.5	V	
		Differential		(V+) - (V-) + 0.2	v	
	Input current, all pins			±10	mA	
	Output short circuit ⁽²⁾		Continuous	Continuous		
T _A	Operating temperature		-55	150	°C	
TJ	Junction temperature		-55	150	°C	
T _{stg}	Storage temperature		-65	150	°C	

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
V _(ESD)	Liechostatic discharge	Charged device model (CDM) per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±500	v

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM MAX	UNIT
Vs	Supply voltage Single-supply Dual-supply Dual-supply	Single-supply	1.7	5.5	- V
		Dual-supply	±0.85	±2.75	
T _A	Specified temperature		-40	125	°C



6.4 Thermal Information - OPA392

			OPA392		
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	DCK (SC70)	YBJ (DSBGA)	UNIT
		5 PINS	5 PINS	6 PINS	
R _{0JA}	Junction-to-ambient thermal resistance	187.1	220.8	135.0	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	107.4	124.4	1.1	°C/W
R _{θJB}	Junction-to-board thermal resistance	57.5	72.9	38.8	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	33.5	46.1	0.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	57.1	72.6	38.8	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Thermal Information - OPA2392

			OPA	2392		
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DGK (VSSOP)	DSG (WSON)	YBJ (DSBGA)	UNIT
		8 PINS	8 PINS	8 PINS	9 PINS	1
R _{θJA}	Junction-to-ambient thermal resistance	131.7	165	70.9	110.7	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	71.4	53	88.3	0.7	°C/W
R _{θJB}	Junction-to-board thermal resistance	75.2	87	37.5	32.1	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	21.8	4.9	2.9	0.3	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	74.4	85	37.5	32.1	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	12.8	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



6.6 Electrical Characteristics

at $T_A = 25^{\circ}$ C, $V_S = 1.7$ V to 5.5 V (single-supply) or $V_S = \pm 0.85$ V to ± 2.75 V (dual-supply), $R_L = 10$ k Ω connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP MAX	UNIT			
OFFSET V	OLTAGE			·					
					±1 ±10				
		V _S = 5.0 V	OPA2392D		±1 ±20				
		vg - 5.0 v	OPA392YBJ, OPA2392YBJ		±1 ±25				
		V _S = 5.0 V,			±2 ±30				
V _{OS}	Input offset voltage	$V_{CM} = (V+) - 200 \text{ mV}$	OPA2392YBJ		±2 ±85	μV			
		$V_{S} = 5.0 V,$ $T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C^{(1)}$			±100				
		$V_{CM} = V_{-},$ $T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C^{(1)}$	OPA392, OPA2392D, OPA2392YBJ		±125				
		$T_A = -40 \text{ C to + 125 C(*)}$	OPA2392DGK		±180				
			T _A = 0°C to 85°C	±	0.16				
dV _{OS} /dT	Input offset voltage drift	V _S = 5.0 V	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C^{(1)}$		±0.6	µV/°C			
			$V_{CM} = 5.0 V,$ $T_A = -40^{\circ}C \text{ to } +125^{\circ}C^{(1)}$	±	0.18 ±0.9	р <i>.,</i> с			
	Power supply rejection				±30				
PSRR	ratio	V _{CM} = V-	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C^{(1)}$		±80	μV/V			
NPUT BIA	SCURRENT								
				±	0.01 ±0.8				
I _B	Input bias current ⁽¹⁾	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			±5	pА			
		T _A = -40°C to +125°C			±30				
				±	0.01 ±0.8				
los	Input offset current ⁽¹⁾	T _A = -40°C to +85°C			±5	pA			
		$T_A = -40^{\circ}C$ to +125°C			±30				
NOISE	I								
					2.0				
	Input voltage noise	f = 0.1 Hz to 10 Hz	$V_{CM} = (V+) - 0.3$		3.2	μV _{PP}			
					42				
		f = 10 Hz	$V_{CM} = (V+) - 0.3$		80				
					6.5				
₽N	Input voltage noise density	f = 1 kHz	$V_{CM} = (V+) - 0.3$		10.4	nV/√Hz			
					4.4				
		f = 10 kHz	V _{CM} = (V+) – 0.3		5.8				
			OPA392DBV		70				
N	Input current noise density	f = 1 kHz	OPA392YBJ, OPA2392		25	fA/√Hz			
	LTAGE								
/ _{CM}	Common-mode voltage range			V–	V+	V			
				75	120				
	Common-mode rejection	$(V-) < V_{CM} < (V+) - 1.5 V$	T _A = -40°C to +125°C		113				
CMRR	ratio	$(V_{-}) < V_{CM} < (V_{+}).$		66	97	dB			
		$(V-) < V_{CM} < (V+),$ $T_A = -40^{\circ}C \text{ to } +125^{\circ}C^{(1)}$	V _S = 5.5 V	88	111				
NPUT CA	PACITANCE	1							
Z _{ID}	Differential			10 ¹³	2.8	Ω ∥ pF			
Z _{ICM}	Common-mode			10 ¹³		Ω pF			



6.6 Electrical Characteristics (continued)

at $T_A = 25^{\circ}$ C, $V_S = 1.7$ V to 5.5 V (single-supply) or $V_S = \pm 0.85$ V to ± 2.75 V (dual-supply), $R_L = 10$ k Ω connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP	MAX	UNIT
OPEN-LOC	DP GAIN						
			(V–) + 50 mV < V _{OUT} < (V+) – 50 mV	115	132		
		V _S = 5.5 V	$(V-) + 100 \text{ mV} < V_0 < (V+) - 100 \text{ mV}, R_L = 2 \text{ k}\Omega$	110	128		
				100			
A _{OL}	Open-loop voltage gain		(V–) + 50 mV < V _{OUT} < (V+) – 50 mV, V _{CM} = (V+) – 1.15 V	106	124		dB
		V _S = 1.7 V	$\begin{array}{l} (V-) + 100 \text{ mV} < V_{OUT} < \\ (V+) - 100 \text{ mV}, \text{ R}_{L} = 2 \text{ k}\Omega, \\ V_{CM} = (V+) - 1.15 \text{ V} \end{array}$	106	124		
			$\begin{array}{l} (V-) + 100 \mbox{ mV} < V_{OUT} < \\ (V+) - 100 \mbox{ mV}, R_L = 2 \mbox{ k} \Omega, \\ V_{CM} = (V+) - 1.15 \mbox{ V}, \\ T_A = -40^{\circ} \mbox{C} \mbox{ to} + 125^{\circ} \mbox{C}^{(1)} \end{array}$	100			
FREQUEN	CY RESPONSE						
GBW	Gain-bandwidth product	A _V = 1000 V/V			13		MHz
SR	Slew rate	4-V step, gain = +1	falling		4.5		V/µs
			rising		3.5		v/µs
	Phase margin $C_1 = 100 \text{pF}$	C. = 100 pE	OPA392DBV, DCK, OPA2392DSG		45		٥
	T hase margin		OPA392YBJ, OPA2392D, DGK, YBJ		35		
ts	Settling time	To 0.1%, 2-V step, gain =	+1		0.75		μs
is		To 0.01%, 2-V step, gain =	= +1		1		μο
	Overload recovery time	V _{IN} × gain > V _S			0.45		μs
THD+N	Total harmonic distortion +	V _{OUT} = 1 V _{RMS} , gain = +1,	f = 1 kHz,		-112		dB
	noise	V _{CM} = (V–) + 1.5 V			0.00025		%
OUTPUT							
		V _S = 1.7 V				20	
	Voltage output swing from		$R_L = 2 k\Omega$			30	mV
	both rails	V _S = 5.5 V				20	
			$R_L = 2 k\Omega$			35	
I _{SC}	Short-circuit current	Sinking, V _S = 5.5 V			-55		mA
		Sourcing, V _S = 5.5 V			65		
R ₀	Open-loop output impedance	f = 1 MHz			120		Ω
POWER SI	JPPLY						
l _Q	Quiescent current per amplifier	I _O = 0 mA	$T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C^{(1)}$		1.22	1.4 1.5	mA



6.6 Electrical Characteristics (continued)

at T_A = 25°C, V_S = 1.7 V to 5.5 V (single-supply) or V_S = ± 0.85 V to ± 2.75 V (dual-supply), R_L = 10 k Ω connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

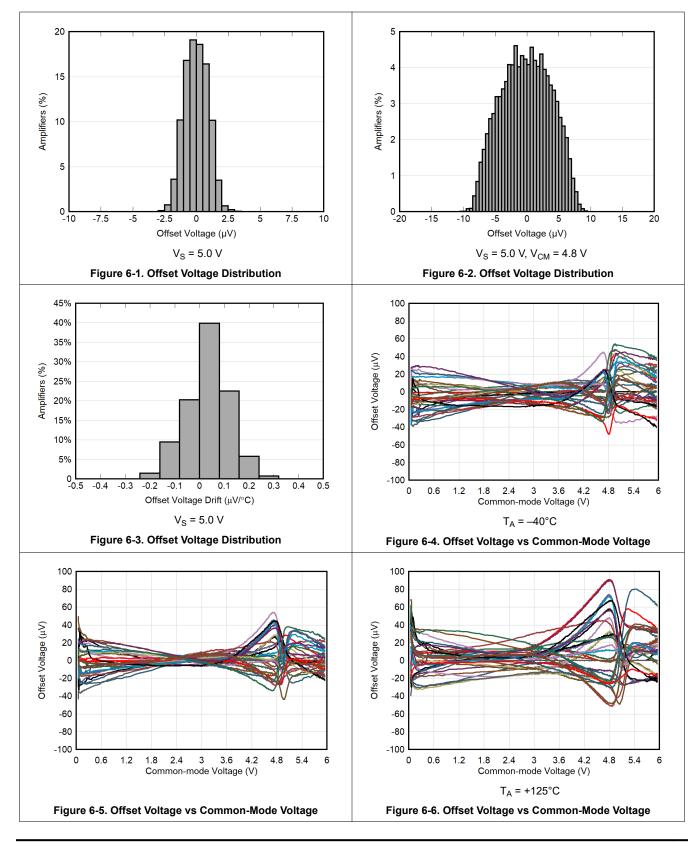
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SHUTDO	WN (OPA392YBJ, OPA2392YB	J and OPA4392RTE Only)			•	
I _{QSD}	Quiescent current per amplifier	All amplifiers disabled, EN = V-		6		μA
VIH	High-level input voltage	Amplifier enabled	(V+)-0.5			V
VIL	Low-level input voltage	Amplifier disabled			(V–) + 0.5	V
t _{ON}	Amplifier enable time	G = 1, V_{OUT} = 0.9 × V_S /2, two amplifiers enabled		9.5		μs
t _{OFF}	Amplifier disable time	G = 1, V_{OUT} = 0.1 × $V_S/2$, two amplifiers disabled		7.8		μs
	EN pin input leakage	V _{IH} = V+		0.02		
	current	V _{IL} = V-		1		μA

(1) Specification established from device population bench system measurements across multiple lots.



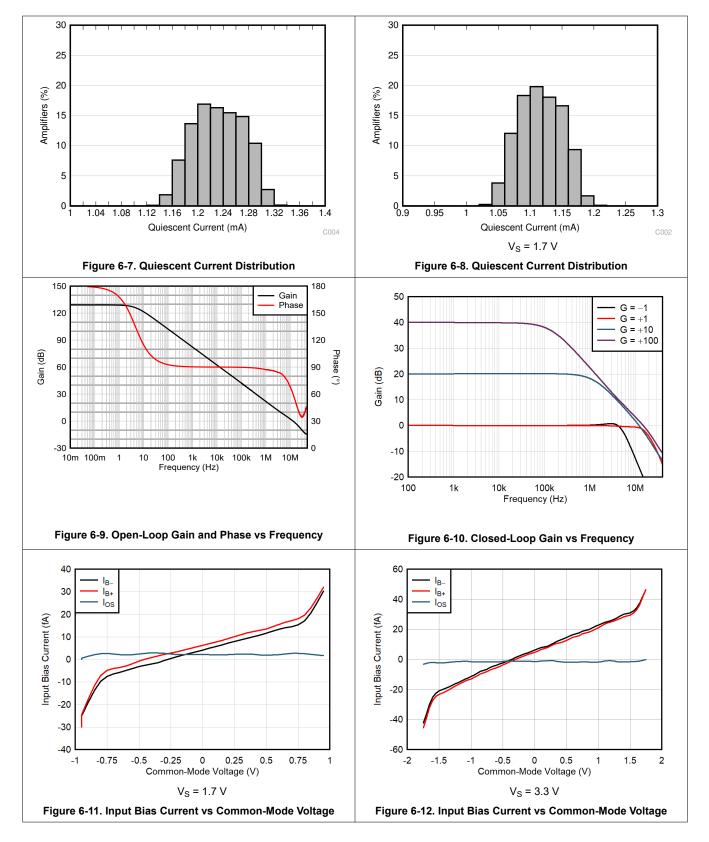
6.7 Typical Characteristics

at $T_A = 25^{\circ}C$, $V_S = 5.5$ V, $V_{CM} = V_S / 2$, $R_{LOAD} = 10$ k Ω connected to $V_S / 2$, and $C_L = 100$ pF (unless otherwise noted)



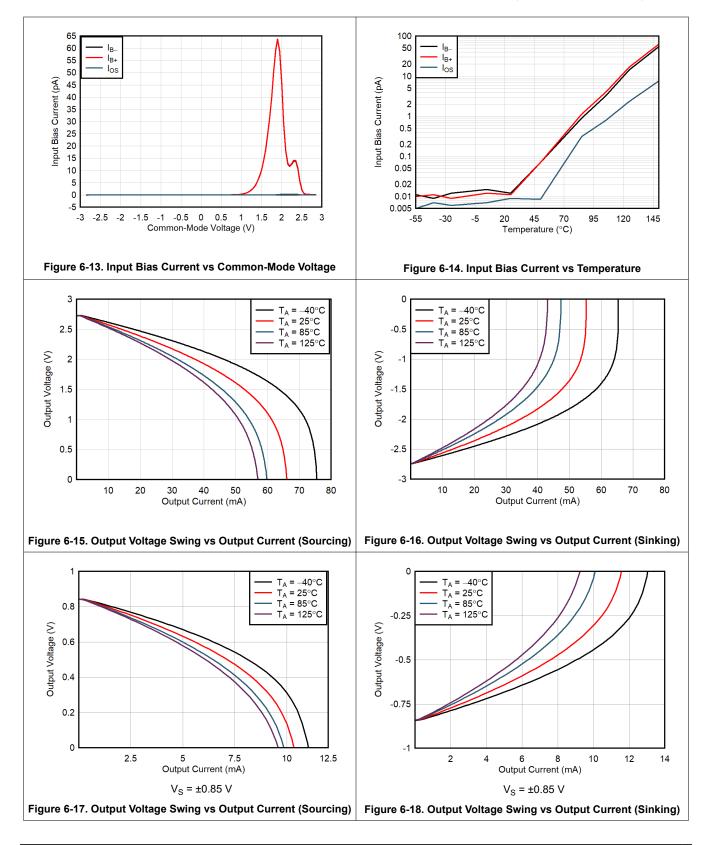


at T_A = 25°C, V_S = 5.5 V, V_{CM} = V_S / 2, R_{LOAD} = 10 k Ω connected to V_S / 2, and C_L = 100 pF (unless otherwise noted)



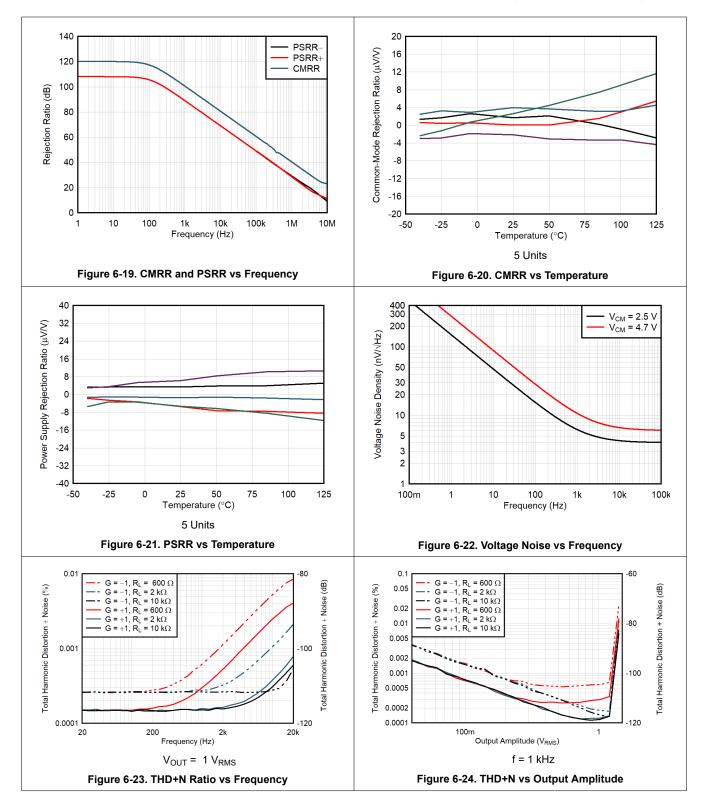


at T_A = 25°C, V_S = 5.5 V, V_{CM} = V_S / 2, R_{LOAD} = 10 k Ω connected to V_S / 2, and C_L = 100 pF (unless otherwise noted)



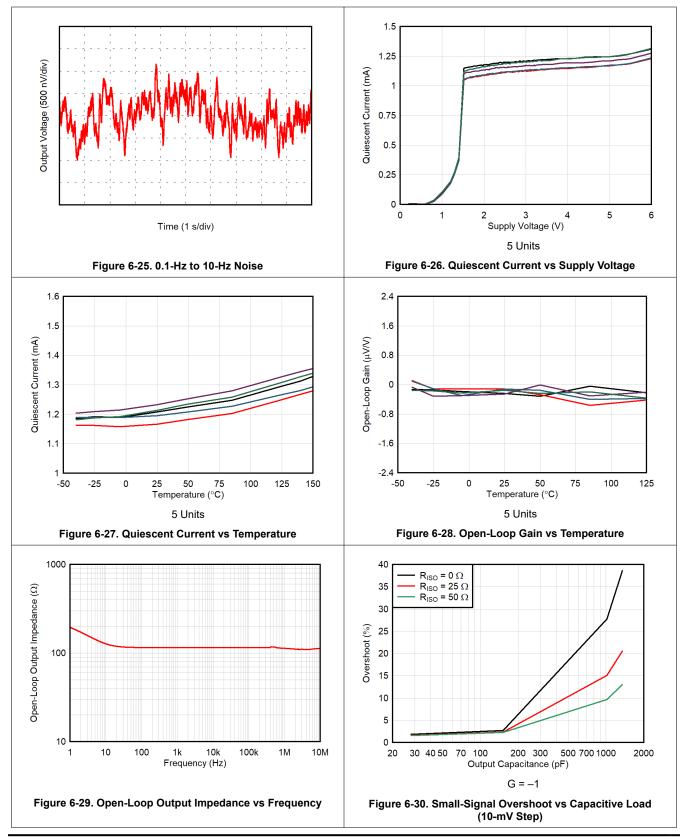


at $T_A = 25^{\circ}C$, $V_S = 5.5$ V, $V_{CM} = V_S / 2$, $R_{LOAD} = 10$ k Ω connected to $V_S / 2$, and $C_L = 100$ pF (unless otherwise noted)





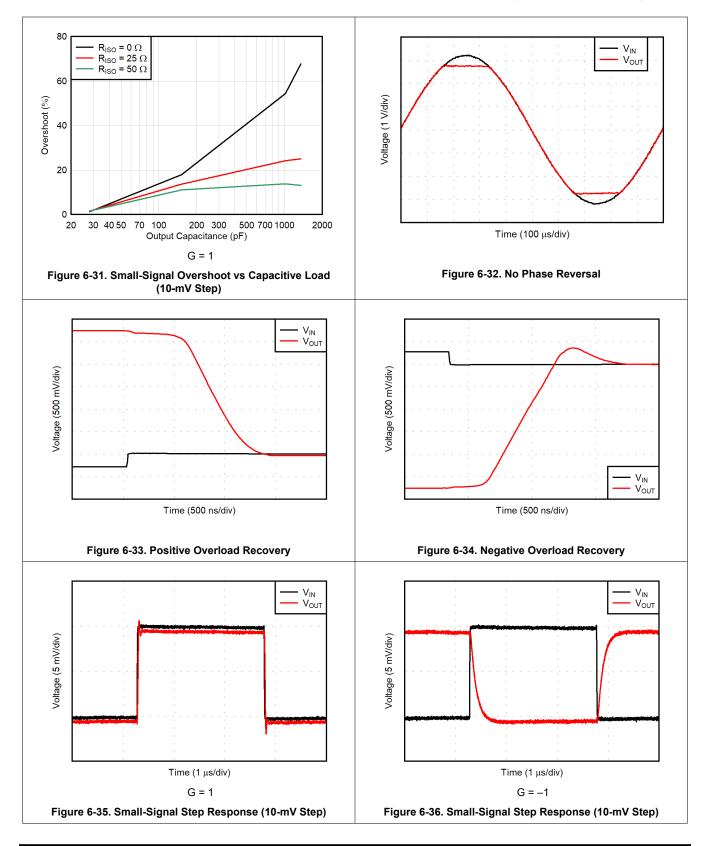
at T_A = 25°C, V_S = 5.5 V, V_{CM} = V_S / 2, R_{LOAD} = 10 k Ω connected to V_S / 2, and C_L = 100 pF (unless otherwise noted)



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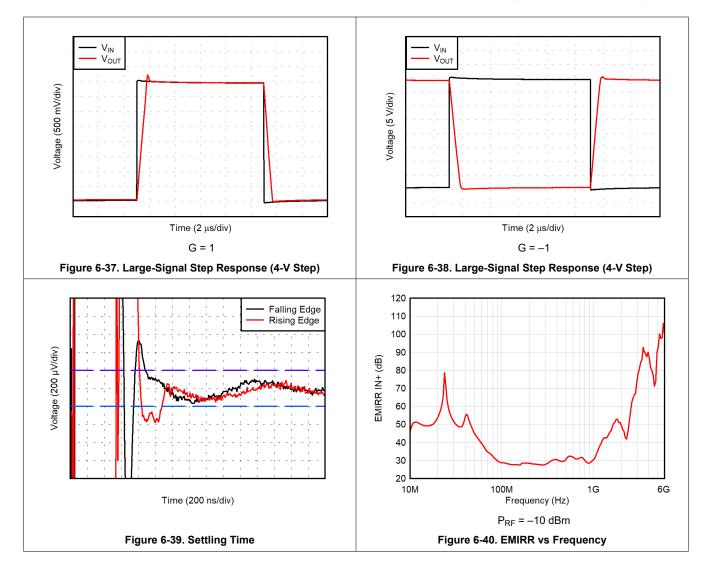


at $T_A = 25^{\circ}C$, $V_S = 5.5$ V, $V_{CM} = V_S / 2$, $R_{LOAD} = 10$ k Ω connected to $V_S / 2$, and $C_L = 100$ pF (unless otherwise noted)





at T_A = 25°C, V_S = 5.5 V, V_{CM} = V_S / 2, R_{LOAD} = 10 k Ω connected to V_S / 2, and C_L = 100 pF (unless otherwise noted)





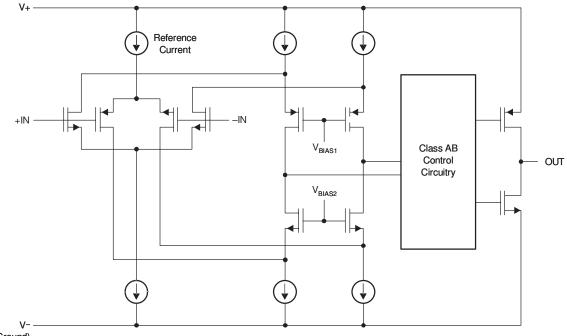
7 Detailed Description

7.1 Overview

The OPAx392 is a family of low offset, low-noise e-trim operational amplifiers (op amps) that uses a proprietary offset trim technique. These op amps offer ultra-low input offset voltage and drift and achieve excellent input and output dynamic linearity. The OPAx392 operate from 1.7 V to 5.5 V, are unity-gain stable, and are designed for a wide range of general-purpose and precision applications.

The amplifiers feature state-of-the-art CMOS technology and advanced design features that help achieve extremely low input bias current, wide input and output voltage ranges, high loop gain, and low, flat output impedance in small package options. The OPAx392 strengths also include 13-MHz bandwidth, $4.4-nV/\sqrt{Hz}$ noise spectral density, and low 1/f noise. These features make the OPAx392 an exceptional choice for interfacing with sensors, photodiodes, and high-performance analog-to-digital converters (ADCs).

7.2 Functional Block Diagram



(Ground)



7.3 Feature Description

7.3.1 Low Operating Voltage

The OPAx392 family can be used with single or dual supplies from an operating range of V_S = 1.7 V (±0.85 V) up to 5.5 V (±2.75 V). The offset voltage is trimmed at 5.0 V, however, the device maintains ultra-low offset voltages down to V_S = 1.7 V.

Key parameters that vary over the supply voltage or temperature range are shown in the Typical Characteristics.

7.3.2 Low Input Bias Current

The typical input bias current of the OPAx392 is extremely low (typically 10 fA). Input bias current is dominated by leakage current from the ESD protection diodes, which is proportional to the area of the diode. The OPAx392 is able to achieve ultra-low input bias current as a result of modern process technology and advanced electrostatic discharge (ESD) protection design that minimizes the area of the diode.

In overdriven conditions, the bias current can increase significantly. The most common cause of an overdriven condition occurs when the operational amplifier is outside of the linear range of operation. When the output of the operational amplifier is driven to one of the supply rails, the feedback loop requirements cannot be satisfied and a differential input voltage develops across the input pins. This differential input voltage results in the forward-biasing of the ESD cells. Figure 7-1 shows the equivalent circuit.

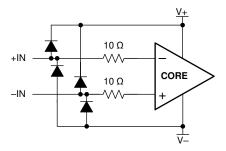


Figure 7-1. Equivalent Input Circuit

7.4 Device Functional Modes

The OPAx392 family is operational when the power-supply voltage is greater than 1.7 V (± 0.85 V). For devices that use the EN function (see Section 5), the devices are disabled when the EN pin is low. In this state, quiescent current is significantly reduced, and the output is high impedance. The maximum specified power-supply voltage for the OPAx392 is 5.5 V (± 2.75 V).



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The OPAx392 is a unity-gain stable, precision operational amplifier family free from unexpected output and phase reversal. The use of proprietary e-trim operational amplifier technology gives the benefit of low input offset voltage over time and temperature, along with ultra-low input bias current. The OPAx392 are optimized for full rail-to-rail input, allowing for low-voltage, single-supply operation or split-supply use. These miniature, high-precision, low-noise amplifiers offer high-impedance inputs that have a common-mode range to the supply rail, with low offset across the supply range, and a rail-to-rail output that swings within 5 mV of the supplies under normal test conditions. The OPAx392 precision amplifiers are designed for upstream analog signal chain applications in low or high gains, as well as downstream signal chain functions such as DAC buffering.

8.2 Typical Application

This single-supply, low-side, bidirectional current-sensing design example detects load currents from -1 A to +1 A. The single-ended output spans from 110 mV to 3.19 V. This design uses the OPA392 because of the low offset voltage and rail-to-rail input and output. One of the amplifiers is configured as a difference amplifier and the other amplifier provides the reference voltage.

Figure 8-1 shows the schematic.

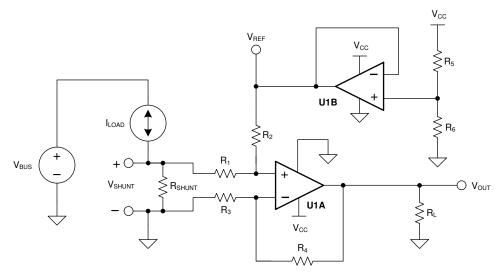


Figure 8-1. Bidirectional Current-Sensing Schematic



8.2.1 Design Requirements

This design example has the following requirements:

- Supply voltage: 3.3 V
- Input: –1 A to +1 A
- Output: 1.65 V ±1.54 V (110 mV to 3.19 V)

8.2.2 Detailed Design Procedure

The load current, I_{LOAD} , flows through the shunt resistor, R_{SHUNT} , to develop the shunt voltage, V_{SHUNT} . The shunt voltage is then amplified by the difference amplifier consisting of U1A and R_1 through R_4 . The gain of the difference amplifier is set by the ratio of R_4 to R_3 . To minimize errors, set $R_2 = R_4$ and $R_1 = R_3$. The reference voltage, V_{REF} , is supplied by buffering a resistor divider using U1B. The transfer function is given by Equation 1.

$$V_{OUT} = V_{SHUNT} \times Gain_{Diff_Amp} + V_{REF}$$
(1)

where

• $V_{SHUNT} = I_{LOAD} \times R_{SHUNT}$

$$Gain_{Diff_Amp} = \frac{R_4}{R_3}$$

 $V_{\text{REF}} = V_{\text{CC}} \times \left[\frac{R_6}{R_5 + R_6} \right]$

There are two types of errors in this design: offset and gain. Gain errors are introduced by the tolerance of the shunt resistor and the ratios of R_4 to R_3 and, similarly, R_2 to R_1 . Offset errors are introduced by the voltage divider (R_5 and R_6) and how closely the ratio of R_4 / R_3 matches R_2 / R_1 . The latter value affects the CMRR of the difference amplifier, ultimately translating to an offset error.

The value of V_{SHUNT} is the ground potential for the system load because V_{SHUNT} is a low-side measurement. Therefore, a maximum value must be placed on V_{SHUNT} . In this design, the maximum value for V_{SHUNT} is set to 100 mV. Equation 2 calculates the maximum value of the shunt resistor given a maximum shunt voltage of 100 mV and maximum load current of 1 A.

$$R_{SHUNT(Max)} = \frac{V_{SHUNT(Max)}}{I_{LOAD(Max)}} = \frac{100 \text{ mV}}{1 \text{ A}} = 100 \text{ m}\Omega$$
(2)

The tolerance of R_{SHUNT} is directly proportional to cost. For this design, a shunt resistor with a tolerance of 0.5% is selected. If greater accuracy is required, select a 0.1% resistor or better.

The load current is bidirectional; therefore, the shunt voltage range is -100 mV to +100 mV. This voltage is divided down by R₁ and R₂ before reaching the operational amplifier, U1A. Make sure that the voltage present at the noninverting node of U1A is within the common-mode range of the device. Therefore, use an operational amplifier, such as the OPA392, that has a common-mode range that extends below the negative supply voltage. Finally, to minimize offset error, the OPA392 has a typical offset voltage of merely ±0.25 μ V (±5 μ V maximum).

Given a symmetric load current of -1 A to +1 A, the voltage divider resistors (R₅ and R₆) must be equal. To be consistent with the shunt resistor, a tolerance of 0.5% is selected. To minimize power consumption, $10-k\Omega$ resistors are used.



To set the gain of the difference amplifier, the common-mode range and output swing of the OPA392 must be considered. Equation 3 and Equation 4 depict the typical common-mode range and maximum output swing, respectively, of the OPA392 given a 3.3-V supply.

$$-100 \text{ mV} < V_{CM} < 3.4 \text{ V}$$
 (3)

$$100 \text{ mV} < V_{\text{OUT}} < 3.2 \text{ V}$$
 (4)

The gain of the difference amplifier can now be calculated as shown in Equation 5:

$$Gain_{Diff_{Amp}} = \frac{V_{OUT_{Max}} - V_{OUT_{Min}}}{R_{SHUNT} \times (I_{MAX} - I_{MIN})} = \frac{3.2 \text{ V} - 100 \text{ mV}}{100 \text{ m}\Omega \times [1 \text{ A} - (-1 \text{ A})]} = 15.5 \frac{\text{V}}{\text{V}}$$
(5)

The resistor value selected for R_1 and R_3 is 1 k Ω . 15.4 k Ω is selected for R_2 and R_4 because this number is the nearest standard value. Therefore, the calculated gain of the difference amplifier is 15.4 V/V.

The gain error of the circuit primarily depends on R_1 through R_4 . As a result of this dependence, 0.1% resistors are selected. This configuration reduces the likelihood that the design requires a two-point calibration. A simple one-point calibration, if desired, removes the offset errors introduced by the 0.5% resistors.

8.2.3 Application Curve

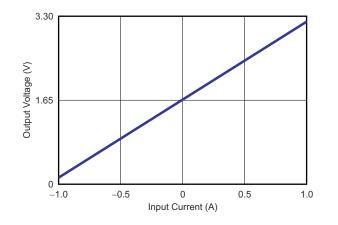


Figure 8-2. Bidirectional Current-Sensing Circuit Performance: Output Voltage vs Input Current



8.3 Power Supply Recommendations

The OPAx392 are specified for operation from 1.7 V to 5.5 V (±0.85 V to ±2.75 V).

CAUTION

Exceeding supply voltages listed in the *Absolute Maximum Ratings* table can permanently damage the device.

8.4 Layout

8.4.1 Layout Guidelines

Pay attention to good layout practice. Keep traces short, and when possible, use a printed-circuit board (PCB) ground plane with surface-mount components placed as close to the device pins as possible. Place a 0.1-µF capacitor closely across the supply pins. These guidelines must be applied throughout the analog circuit to improve performance and provide benefits such as reducing the electromagnetic interference (EMI) susceptibility.

For lowest offset voltage and precision performance, circuit layout and mechanical conditions must be optimized. Avoid temperature gradients that create thermoelectric (Seebeck) effects in the thermocouple junctions formed from connecting dissimilar conductors. These thermally-generated potentials can be made to cancel by making sure these potentials are equal on both input terminals. Other layout and design considerations include:

- Use low thermoelectric-coefficient conditions (avoid dissimilar metals).
- Use guard traces to minimize leakage current when ultra-low bias current is required.
- Thermally isolate components from power supplies or other heat sources.
- Shield operational amplifier and input circuitry from air currents, such as cooling fans.

Following these guidelines reduces the likelihood of junctions being at different temperatures, which can cause thermoelectric voltage drift of $0.1 \,\mu\text{V}/^{\circ}\text{C}$ or higher, depending on materials used.

8.4.2 Layout Example

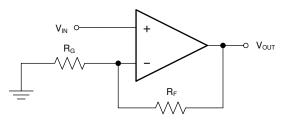


Figure 8-3. OPA392 Layout Schematic

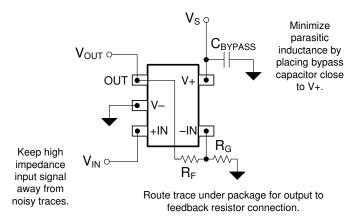


Figure 8-4. OPA392 Layout Example



9 Device and Documentation Support

9.1 Device Support

9.1.1 Development Support

9.1.1.1 PSpice[®] for TI

PSpice[®] for TI is a design and simulation environment that helps evaluate performance of analog circuits. Create subsystem designs and prototype solutions before committing to layout and fabrication, reducing development cost and time to market.

9.1.1.2 TINA-TI™ Simulation Software (Free Download)

TINA-TI[™] simulation software is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI simulation software is a free, fully-functional version of the TINA[™] software, preloaded with a library of macromodels, in addition to a range of both passive and active models. TINA-TI simulation software provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Design and simulation tools web page, TINA-TI simulation software offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

Note

These files require that either the TINA software or TINA-TI software be installed. Download the free TINA-TI simulation software from the TINA-TI™ software folder.

9.2 Documentation Support

9.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, Amplifier Input Common-Mode and Output-Swing Limitations application note
- Texas Instruments, Offset Correction Methods: Laser Trim, e-Trim™, and Chopper application brief

9.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.4 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.5 Trademarks

e-trim[™], TINA-TI[™], and TI E2E[™] are trademarks of Texas Instruments. TINA[™] is a trademark of DesignSoft, Inc. PSpice[®] is a registered trademark of Cadence Design Systems, Inc. All trademarks are the property of their respective owners.



9.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision G (April 2024) to Revision H (November 2024)	Page
•	Changed status of OPA392 DCK (SC70, 5) and OPA2392 DSG (WSON, 8) packages from preview to production data (active) and added associated content	1
•	Changed max V _{OS} of OPA2392DGK for overtemperature range condition from ±125µV to ±180µV base the latest characterization data	ed on
•	Changed typical phase margin specification of OPA392YBJ and OPA2392D, DGK, and YBJ from 45° to based on the latest characterization data	o 35°

CI	hanges from Revision F (December 2023) to Revision G (April 2024)	Page
•	Changed OPA2392 DGK (VSSOP, 8) package status from advanced information (preview with samples) to
	production data (active) and added associated content	1

C	hanges from Revision E (September 2023) to Revision F (December 2023)	Page
•	Changed OPA392 YBJ (DSBGA, 6) package status from advanced information (preview with samples) production data (active) and added associated content	
•	Changed OPA2392 D (SOIC, 8) package status from preview to production data (active) and added associated content.	1
•	Changed OPA2392 DGK (VSSOP, 8) package status from preview to advanced information (preview w samples) and added associated content	

11 Mechanical, Packaging, and Orderable Information

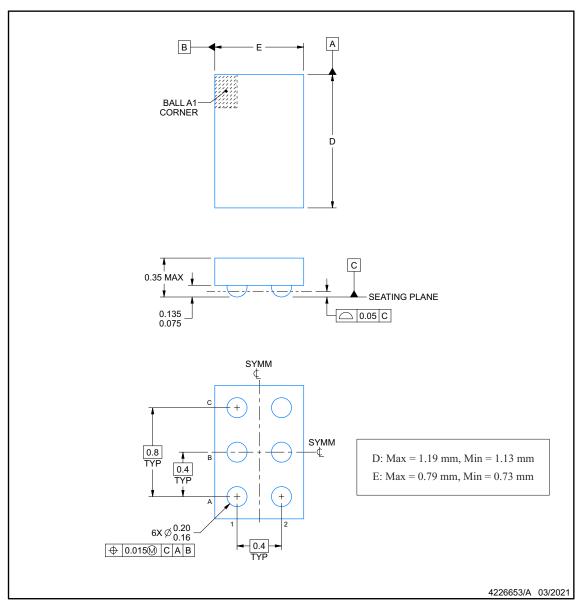
The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGE OUTLINE

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
This drawing is subject to change without notice.

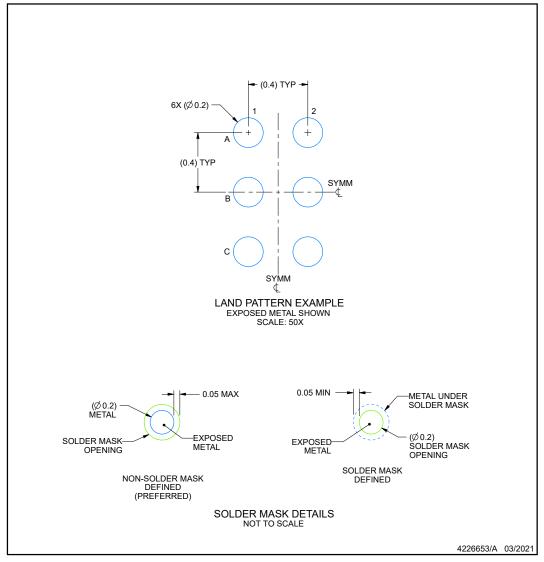




EXAMPLE BOARD LAYOUT

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

 Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).



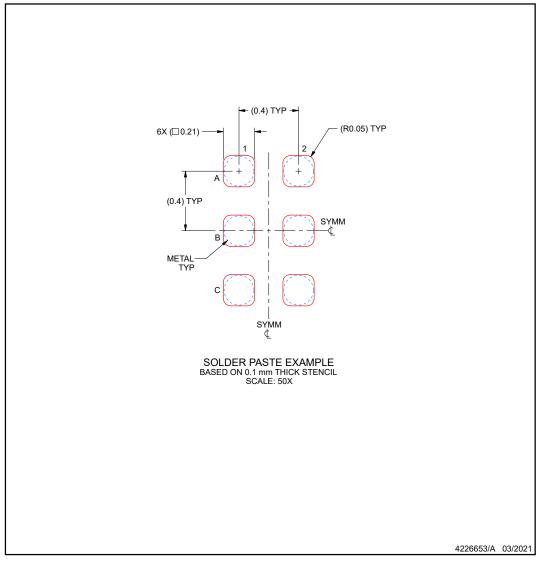


EXAMPLE STENCIL DESIGN

YBJ0006

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OPA2392DGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	(6) NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3BJS	Samples
OPA2392DR	ACTIVE	SOIC	D	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	O2392D	Samples
OPA2392DSGR	ACTIVE	WSON	DSG	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3B8H	Samples
OPA2392YBJR	ACTIVE	DSBGA	YBJ	9	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125	O23	Samples
OPA2392YBJT	ACTIVE	DSBGA	YBJ	9	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125	O23	Samples
OPA392DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	23GT	Samples
OPA392DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	23GT	Samples
OPA392DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QL	Samples
OPA392YBJR	ACTIVE	DSBGA	YBJ	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125	PL	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



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PACKAGE OPTION ADDENDUM

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2392DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2392DR	SOIC	D	8	3000	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2392DSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
OPA2392YBJR	DSBGA	YBJ	9	3000	180.0	8.4	1.26	1.26	0.43	4.0	8.0	Q1
OPA2392YBJT	DSBGA	YBJ	9	250	180.0	8.4	1.26	1.26	0.43	4.0	8.0	Q1
OPA392DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA392DBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA392DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
OPA392YBJR	DSBGA	YBJ	6	3000	180.0	8.4	0.85	1.27	0.43	2.0	8.0	Q1



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PACKAGE MATERIALS INFORMATION

12-Dec-2024



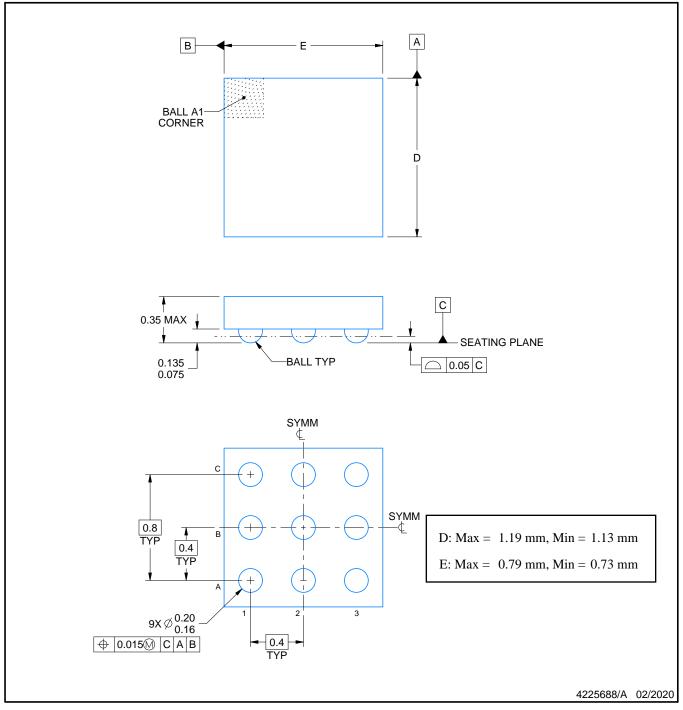
	ù	,					
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2392DGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
OPA2392DR	SOIC	D	8	3000	356.0	356.0	35.0
OPA2392DSGR	WSON	DSG	8	3000	210.0	185.0	35.0
OPA2392YBJR	DSBGA	YBJ	9	3000	182.0	182.0	20.0
OPA2392YBJT	DSBGA	YBJ	9	250	182.0	182.0	20.0
OPA392DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA392DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA392DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
OPA392YBJR	DSBGA	YBJ	6	3000	182.0	182.0	20.0



PACKAGE OUTLINE

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

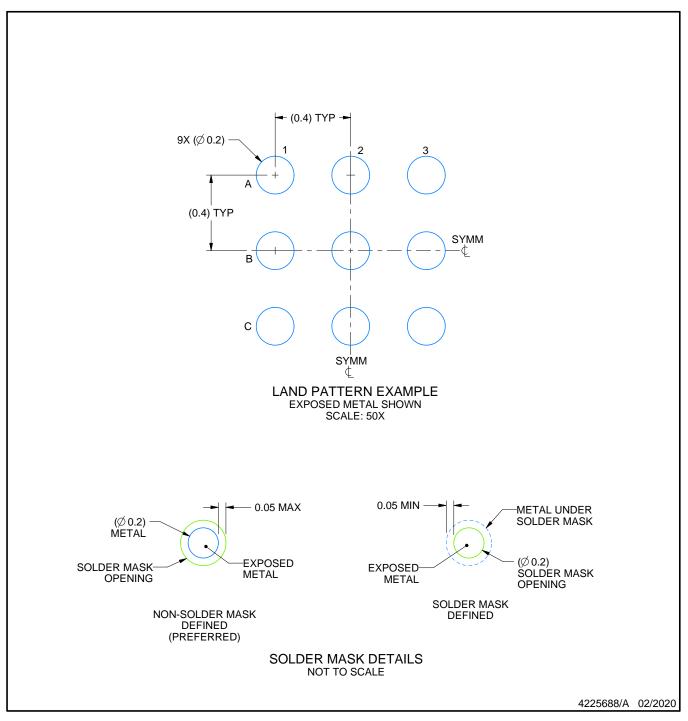
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.



EXAMPLE BOARD LAYOUT

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

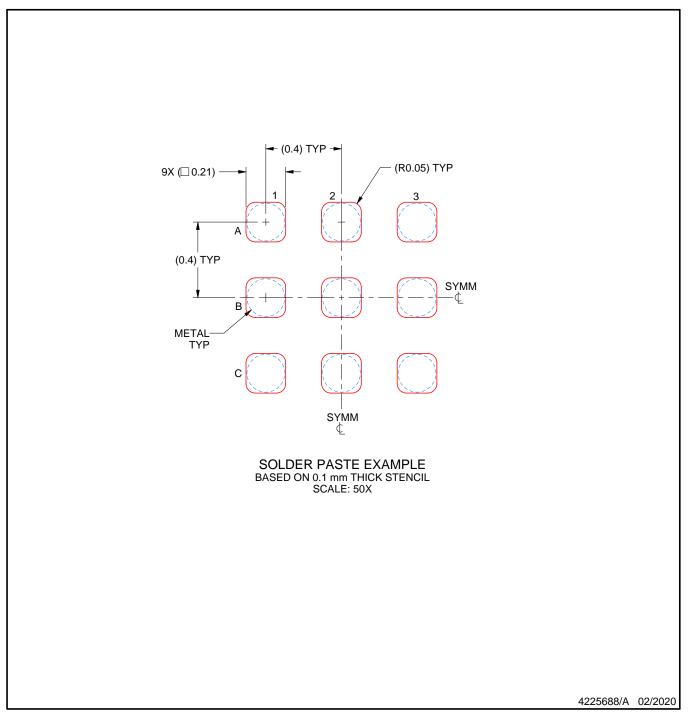
 Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).



EXAMPLE STENCIL DESIGN

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



DCK0005A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



DCK0005A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

Publication IPC-7351 may have alternate designs.
Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DCK0005A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



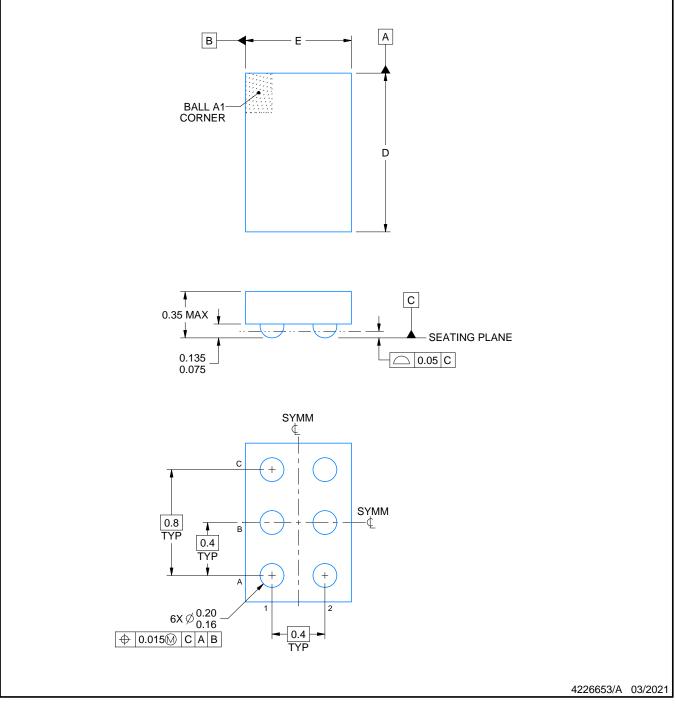
YBJ0006



PACKAGE OUTLINE

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

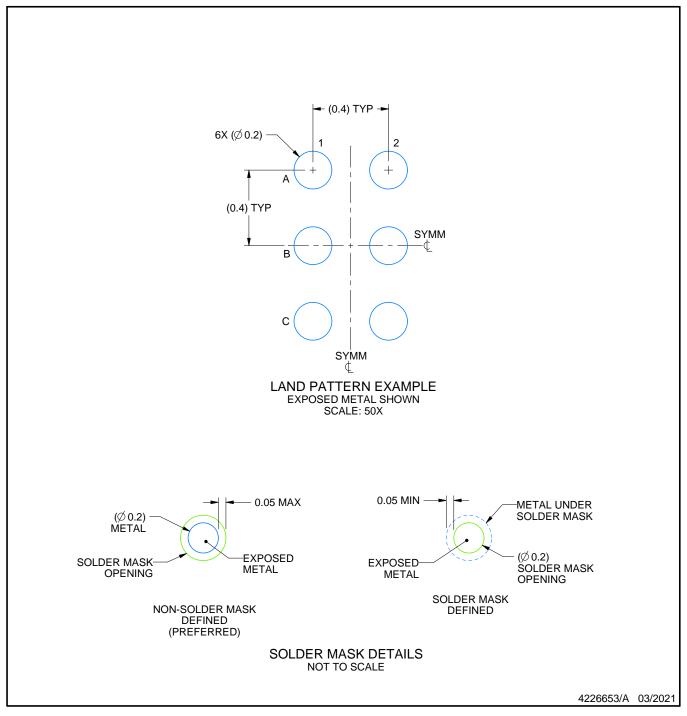


YBJ0006

EXAMPLE BOARD LAYOUT

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

 Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).

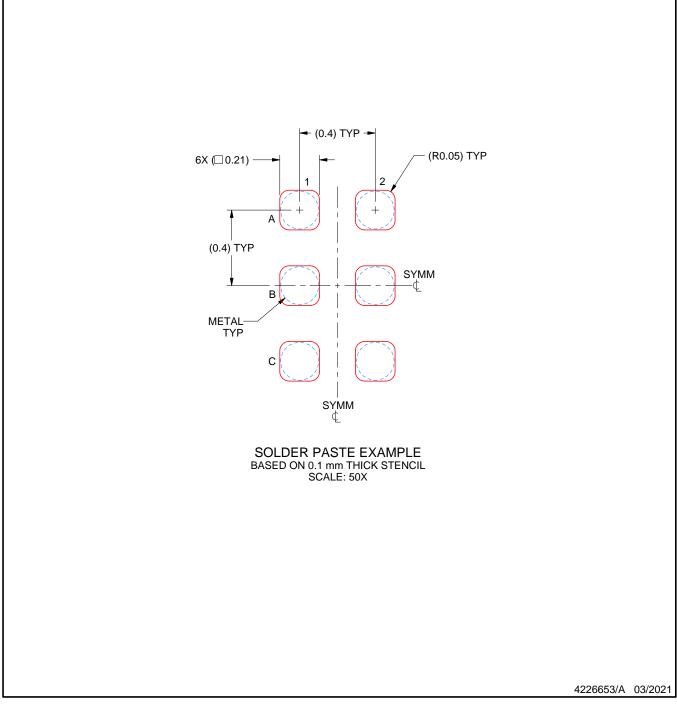


YBJ0006

EXAMPLE STENCIL DESIGN

DSBGA - 0.35 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



DSG 8

2 x 2, 0.5 mm pitch

GENERIC PACKAGE VIEW

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





DSG0008A



PACKAGE OUTLINE

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



DSG0008A

EXAMPLE BOARD LAYOUT

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

 This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

 Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



DSG0008A

EXAMPLE STENCIL DESIGN

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



DGK0008A

EXAMPLE BOARD LAYOUT

[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown

on this view. It is recommended that vias under paste be filled, plugged or tented.

9. Size of metal pad may vary due to creepage requirement.



DGK0008A

EXAMPLE STENCIL DESIGN

[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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